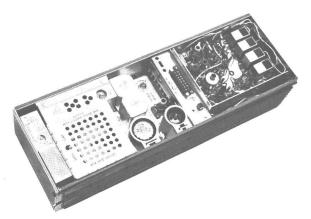


MASTR PROGRESS LINE

406-470 MHz, TRANSMITTER MODELS 4ET59C30-41, 4ET59F10-13 & 4ET60C30-41



SPECIFICATIONS *

FCC Filing Designation:

ET-59-C

Frequency Range:

406-420 & 450-470 MHz

Power Output:

35 watts minimum (20 watts minimum in 6-volt systems)

ET-59-F

450-470 MHz

12 watts minimum

ET-60-C

406-420 & 450-470 MHz

70 watts minimum

Crystal Multiplication Factor:

36

36

Frequency Stability:

 $\pm 0.0002\%$ (-35°C to +60°C)

Modulation:

Adjustable from 0 to ± 5 kHz (Narrow Band) and 0 to ± 15 kHz (Wide Band) swing with instantaneous modulation limiting.

Audio Frequency Characteristics

Within +1 dB to -3 dB of a 6 dB/octave pre-emphasis from 300 to 3000 Hertz per EIA standards. Post limiter filter per FCC and EIA.

Distortion:

Less than 5%

Tubes & Transistors:

Transmitter with no Options:

3 tubes

6 silicon transistors 4 diodes & 2 varactors

1 ICOM module

Maximum Frequency Spacing:

0.2%

Duty Cycle:

Mobile-

20% transmit (one minute transmit, four minutes off)

Station-

Continuous

*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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WARNING -

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

DESCRIPTION

The MASTR Progress Line FM Transmitters Types ET-59-C, ET-59-F and ET-60-C are crystal-controlled, phase-modulated transmitters designed for one-through four-frequency operation within the 406-420 and 450-470 megahertz bands. The transmitters were designed for either narrow-band or wideband operation, and consist of the following modules:

- Transistorized Exciter Board, with audio, modulator, amplifier, and multiplier stages.
- Integrated Circuit Oscillator Module (ICOM).
- Multipliers, IPA and power amplifier stages.
- Optional transistorized Channel Guard Low-Pass Filter.

All input leads to the transmitters are individually filtered by the 20-pin feed-through by-pass connector J101. The output passes through a two-section, band-pass filter, followed by a low-pass filter.

from 11.25 to 11.67 megahertz (low-split), and 12.5 to 13.05 megahertz (high-split). The oscillator frequency is multiplied 36 times.

A centralized metering jack (J102) is provided for use with General Electric Test Sets 4EX3A10 or 4EX8K11. The Test Set meters the multiplier, amplifier and PA stages as well as filament and regulated supply voltages. The metering jack also provides access to audio microphone and push-to-talk leads.

POWER INPUTS

The following supply voltages are connected from the power supply to the transmitter through the 20-pin by-pass connector J101:

- Pin 3: Filament
- Pin 4: +300 volts MULT & IPA B+
- Pin 5: PA B+
- Pin 8: -45 volts bias
- Pin 14: +10 volts for Channel Guard option
- Pin 15: -20 volts for Exciter Board and ICOM module

CIRCUIT ANALYSIS

Six silicon transistors and only three tubes are used in the transmitters. The frequency of the plug-in ICOM modules ranges

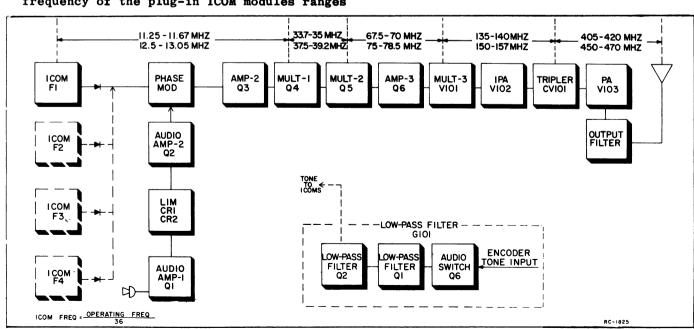


Figure 1 - Transmitter Block Diagram

NOTE -

The PA B-plus voltage will vary due to the different power supplies used (both mobile and station), and due to the power input limitations of different services. Refer to the PA Plate Voltage Chart on the Transmitter Schematic Diagram for the different operating conditions.

ICOM MODULE

ICOM module Model 4EG25Al0 consists of a crystal-controlled Colpitts oscillator, a voltage regulator, a Channel Guard tone modulator and a buffer output stage. The entire module (including crystal) is enclosed in a dust-proof aluminum can, with the ICOM frequency and the transmitter operating frequency printed on the top. Access to the oscillator trimmer is obtained by prying off the plastic GE decal on the top of the can.

The oscillator frequency is temperature-compensated at both ends of the temperature range to provide instant frequency compensation, with a frequency stability of $\pm .0002\%$.

In single-frequency transmitters, a keying jumper from H1 to H2 (on the exciter board) connects the ICOM to ground. This drops the -20 volts exciter supply through voltage dividers R19 and R20 to provide -10 volts to operate the ICOM. With the ICOM operating, diode CR3 is forward biased and the oscillator output is applied to the modulator stage.

In multi-frequency transmitters, up to three additional ICOM modules can be plugged into the exciter board. The single-frequency keying jumper is removed, and the proper frequency is selected by switching the ICOM keying lead to ground by means of a frequency selector switch on the control unit.

In Channel Guard applications, tone from the low-pass filter board is applied to the ICOM through Channel Guard Mod Adjust R1002. The oscillator output is frequency modulated by the Channel Guard tone.

- CAUTION -

All ICOM modules are individually compensated at the factory, and cannot be repaired in the field. Any attempt to remove the ICOM cover will void the warranty.

AUDIO AMPLIFIERS AND LIMITER

An audio signal from the microphone is coupled through Cl to the base of Class

A audio amplifier Q1. The design of the microphone, in conjunction with C2 and R3, produces a 6-dB audio pre-emphasis. RF decoupling is provided by C45.

The amplified audio signal is RC coupled to the diode limiters, CR1 and CR2. These diodes operate in series and are normally in a forward conducting state. An audio signal of sufficient amplitude to cause limiting takes the diodes out of conduction, so that one diode conducts only on positive cycles and the other conducts only on negative cycles.

Following the limiter stage is a second Class A amplifier, Q2. The output of Q2 is coupled through MOD ADJUST potentiometer R12 to a combined post-limiter filter and deemphasis network. This network consists of C4, C7, C8, C9, R13, R14, R15 and R18. The output of the filter and deemphasis network is applied directly to the phase modulator.

PHASE MODULATOR

The phase modulator uses varactor CV1 (voltage variable capacitor) in series with tunable coil L1/L2. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator varies the bias of CV1, resulting in a phase-modulated output. The output of the modulator is coupled through blocking capacitor C14 to the base of the second amplifier.

AMPLIFIERS AND 1ST AND 2ND MULTIPLIERS

The second amplifier (Q3) isolates the modulator from the loading effects of the first multiplier and provides amplification. The output is coupled through T6 to the first multiplier.

Following Q3 are two inductively-coupled Class C, common-emitter multiplier stages (Q4 and Q5). Q4 is a tripler, with collector tank T1 tuned to three times the crystal frequency. Metering resistors R31 and R42 are for metering the MULT-1 stage at centralized metering jack J102.

Q5 operates as a doubler stage, with collector tank T3 tuned to six times the crystal frequency. Resistors R33 and R40 are for metering the MULT-2 stage at J102. The output of Q5 is inductively coupled through T3 and T4 to amplifier Q6. In 450-470 megahertz transmitters, capacitor C29 provides some high-side capacitive coupling.

Third amplifier Q6 is a neutralized straight-through amplifier. Feedback through C35 from the output link on T5 provides neutralization. This stage is metered at J102-3 across R37. The output is coupled to the grid tank of multiplier V101.

3RD MULTIPLIER

The output of the transistorized Exciter is coupled by a short length of RF cable to the grid tank (Z101/Z102) of beam pentode V101. This stage operates as a doubler with the plate tank tuned to twelve times the crystal frequency.

Bias voltage (approximately -18 volts) is supplied to the grid of V101 through R108 to protect the tube against loss of drive. Grid voltage is metered by metering network R105 and R106 with a residual reading of approximately 0.18 volts without any drive, caused by fixed bias voltage to the grid of V101. The plate tank is tuned by C104 with plate voltage supplied through L101.

IPA AND TRIPLER

The output of the MULT-3 stage is coupled by a pi-network consisting of C104, L102/L103 and C107/C108 to the grid of the IPA, a compactron beam power amplifier.

Approximately 45 volts of bias voltage is supplied to the grid of V102 through R112 and a tap on L102/L103 to protect the stage against loss of drive. A residual reading of 0.28 volt without any drive to the stage indicates the presence of fixed bias. Grid voltage and the tripler varactor bias voltage are metered simultaneously at J201-5.

The IPA plate tank is tuned by Cl15, and plate voltage is supplied through L105. The stage is neutralized by Cl10.

RF from the IPA is coupled through C118/C119 to a passive tripler stage. The tripler consists of three tuned stages (C115 & L107/L108, C121 & L110/L111, and C122 & L112/L113) which are coupled together through the common impedance of varactor CV101.

The IPA output is fed to the tripler, where the first tuned stage resonates at the fundamental frequency. The second tuned circuit (an "idler" circuit) is tuned to twice the input signal, and mixes with the input signal to produce the desired third harmonic (or operating frequency). The third tuned circuit is tuned to the operating frequency.

POWER AMPLIFIER

Drive from the tripler stage is link-coupled to the grid circuit of V103 through L115 and L116. V103 is a coaxial element, conduction-cooled beam power tetrode operating as a neutralized Class C amplifier.

The grid line L127/L128 of V103 is series-tuned by C130 with 20 volts of protective bias supplied through L117 and grid bias resistors R103 and R129. PA grid current is metered across resistor R103 at

J102-6 and J102-14.

Neutralization is provided by a fixed series screen inductance (the fingers on the screen by-pass ring) and the screen by-pass capacitors Cl35, Cl36, Cl38 and Cl40.

The PA Plate tank circuit is comprised of C145 (the plate tank tuning flap), L119/L120 (the copper-plated heat sink on the plate of V103), and mechanically constructed capacitor (with mica dielectric) C143. The plate voltage is supplied through choke L122, which is connected to feed-through capacitor C142.

The PA screen voltage is controlled by OUTPUT CONTROL potentiometer R124 which is in series with R123/R126/R131 in the screen supply circuit. With the OUTPUT CONTROL fully counterclockwise, the plate dissipation of V103 is reduced below the rated tube limit for tuning the power amplifier stage.

Plate current is metered from J102-1 to J102-9 across metering resistor R102 in high-power units, transmitter Type ET-60-C. In Type ET-59-C and ET-59-F transmitter, R101 is added in series with R102.

— WARNING --

The meter leads are at plate potential (high B-plus when metering the PA Plate.

The output of V103 is link-coupled to band-pass filter FL101/FL102 consisting of two inductively coupled helical resonators. C1/C2 and C3/C4 are the output tuning capacitors. L5/L6, C5 and C6 form an additional low-pass filter section. The RF output is fed through J103 to the antenna changeover relay located on the front of the system frame.

An RF sniffer circuit (CR1, C7, and R1) provides for measuring the relative power output at J102-11. When troubleshooting the transmitter, components of the low-pass filter and RF sniffer circuit can be checked by removing the plate on the bottom of the filter casing.

CHANNEL GUARD

Low Pass Filter (G101)

In encode-decode combinations, low-pass filter Gl01 is assembled on a printed wiring board that mounts on the underside of the MASTR transmitters. The filter is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied continuously (even in the STANDBY position), and the -20 volts is applied only when the transmitter is keyed.

Keying the transmitter applies the encoder tone (from the receiver) to low-pass

filter G101. Transistors Q1 and Q2 form a two-section, active low-pass filter that reduces tone distortion and power supply ripple. Q6 operates as a tone switch, applying the tone input to the filter whenever +10 volts is applied to J1 (Q6 base). Thermistor RT1 keeps the output constant over wide variations in temperature. The filter output is coupled to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the operational hang-up bracket.

- NOTE -

When Channel Guard decode only is desired, remove the wire that connects to J6 on the Low-Pass filter (Encoder Tone Input).

Encoder Model 4EH17A10 (Optional)

In encode only combinations, or when different encode and decode frequencies are required, optional encoder Model 4EH17A10 mounts on the underside of the MASTR transmitter. The encoder is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied to Q3, Q4 and Q5 continuously (even in the STAND-BY position). The -20 volts is applied to Q1 and Q2 only when the transmitter is keyed.

The encoder tone is provided by selective oscillators Q3 and Q4, which oscillate continuously at a frequency determined by the tone network (FL1). Negative feedback, applied through the tone network to the base of Q3, prevents any gain in the stage except at the desired encode frequency.

Thermistor-resistor combination R14 and RT2 provides temperature compensation for the oscillator output. Limiter diodes CR1 and CR2 keep the tone amplitude constant.

Keying the transmitter applied -20 volts to the two-stage, active low-pass filter (Q1 and Q2) turning them on. The oscillator output is then coupled through emitter-follower Q5 to the low-pass filter. Thermistor RT1 keeps the filter output constant over wide variations in temperatures.

The output of the filter is applied to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the operational hang-up bracket.

MAINTENANCE

DISASSEMBLY

To service the transmitter from the top:

- 1. Pull locking handle down and pull radio about one inch out of mounting frame.
- 2. Pry up cover at rear of transmitter.
- 3. Slide cover back and lift off.

To service the transmitter from the bottom:

- Pull locking handle down and pull radio out of mounting frame.
- Remove the two screws in bottom cover, and pry up at back of transmitter.
- 3. Slide cover back and lift off.

To remove transmitter from system frame:

- Loosen the two retaining screws in the front casting (see Figure 2) and pull away from the system frame.
- 2. Remove the four screws in the back cover.
- 3. Remove the two screws holding the transmitter at each end of the system frame.
- 4. Disconnect the antenna jack in front of the transmitter and the 20-pin feed-thru connector at the back of the transmitter, and slide the unit out of the system frame.

TUBE REPLACEMENT

— WARNING -

Before replacing tubes, remove all power from the unit so that the transmitter cannot be keyed. In mobile units, disconnect power plug P504. In stations, turn off the main line switch and discharge filter capacitors.

To replace 3rd Multiplier and IPA Tubes (V101 & V102)

Loosen the two screws holding tube shield to heatsink, and pull off tube shield. Then carefully work the tube out of its socket.

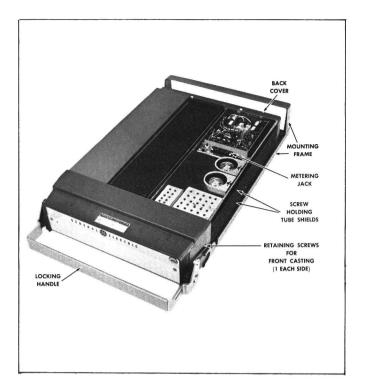


Figure 2 - Top Cover Removed

To replace Power Amplifier V103:

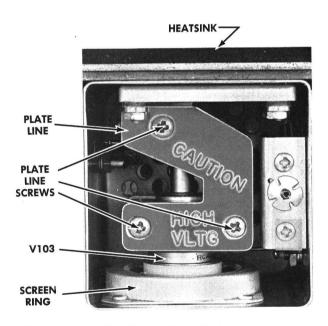


Figure 4 - PA Plate Box With Cover Removed

- Make sure that all power is removed from the unit.
- 2. Remove the top cover on the AMPL PLATE box (fig. 4). Allow the transmitter to cool if necessary.



Figure 3 - Bottom Cover Removed

- 3. Remove the three Phillips-head screws in the plate line, starting with the two screws nearest tube socket. Lift off the top section of the plate line. Next, slide the bottom section toward the AMPL PLATE tuning adjustment and lift it out of the AMPL PLATE box.
- Carefully work the tube out of its socket.
- 5. Use a screwdriver to bend the screen ring contacts out toward the center of the tube socket so that all contacts will touch the base of the tube.

- CAUTION -

Extreme care should be taken during PA tube replacement to avoid damaging the screen ring contacts.

- 6. Replace the tube by hand, making sure that it is fully seated in the socket and that all screen ring contacts are touching the tube.
- 7. Replace the plate lines, tightening the screw nearest the heat-sink first.

 Then replace the top cover of AMPL PLATE box.
- 8. Realign the transmitter.

		•

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R12) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Models 4EX3A10 or 4EX8K11

PROCEDURE

- 1. Connect the audio oscillator and the meter across audio input terminals J5 (Green-Hi) and J6 (Black-Lo) on GE Test Set or across Jl (Mike High) and J2 (Mike Low) on the
- 2. Apply a 0.75-volt signal at 1000 Hz to Test Set or across Jl and J2 on Exciter Board.
- 3. For transmitters without Channel Guard, set the MOD ADJUST (R12) for a 4.5-kilohertz swing (13.5 kHz for wide band) with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set the Channel Guard MOD ADJUST (R1002) for 0.75 kHz tone deviation. Remove the tone to the transmitter by unplugging leads to J7 and J8 on Exciter Board, or by switching to a non-Channel Guard frequency in multifrequency units. Next, apply a 0.75-volt signal at 1000 Hz and set MOD ADJUST (R12) for a 3.75 kHz deviation (4.5 kHz minus 0.75 kHz tone deviation).
- 5. For multi-frequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA Plate voltage and the plate current indication, and using the following formula:

ET-59-C ET-59-F: P_i = Plate Voltage x Plate Current Indication

ET-60-C: $P_i = \frac{\text{Plate Voltage x Plate Current Indication}}{2}$

P; is the power input in watts.

Plate voltage is measured with GE Test Set in position G, using the 1000-volt scale (or measured from J102-1 to -16 with multi-

Plate current indication is measured with GE Test Set in position G, using the TEST 1 scale (or measured from J102-1 to -9 with multimeter).

3.5 or 2.59 is the value of the plate current metering resistor in ohms.

TRANSMITTER ALIGNMENT

EQUIPMENT REQUIRED

1. General Electric Test Set Models 4EX3A10 (TM11 or TM12), 4EX8K11, Station Test Meter Panel, or a 20,000 ohms-per-volt Multimeter with a 1-volt scale.

PRELIMINARY CHECKS AND ADJUSTMENTS

METERING POSITION

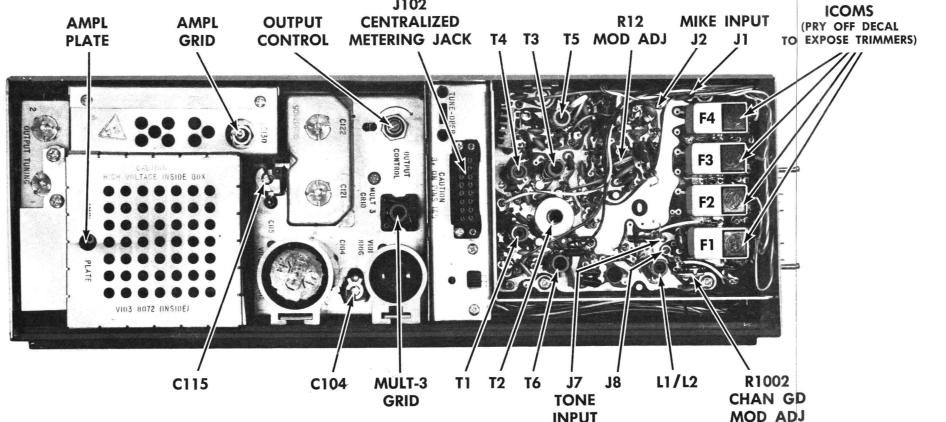
- 1. Place ICOM(s) (operating frequency : 36) in proper socket. Do not adjust ICOM trimmer. In multi-frequency units; tune the transmitter on the lowest frequency (except for Steps 15 and 16)
- 2. Turn OUTPUT CONTROL (R124) fully counterclockwise. This limits PA dissipation during initial tune-up.

METER

- 3. Connect Test Set to the Transmitter Centralized Metering Jack J102. If using Multimeter, connect the positive lead to J102-16 (Ground), except where indicated.
- 4. For a large change in frequency or a badly misaligned transmitter, set the slugs in the Exciter coils at the bottom of the coil form, and the slug of Z101/Z102 (MULT-3 GRID) at the top of the coil form. Tune AMPL PLATE counterclockwise until the stud is even with the top of the case. Then turn C121, C122 and OUTPUT TUNING -1 and -2 fully counterclockwise.
- 5. All adjustments are made with the transmitter keyed.

ALIGNMENT PROCEDURE

Step	4EX3A10	Multimeter - at J102	TUNING CONTROL	METER READING	PROCEDURE
				EXCITE	ER BOARD
1.	A	Pin 10	T6 and L1/L2	0.55 v (0.4 v Minimum)	Tuning the modulator is a critical adjustment. Carefully tune T6 and L1/L2 alternately for maximum meter reading. If no peak is obtained when tuning T6, set the slug in L1/L2 to a different position and re-tune T6.
2.	A (MULT-1)	Pin 10	Tl	See Pro- cedure	Tune Tl for a small dip in meter reading (not required unless changing frequency.
3.	B (MULT-2)	Pin 2	T2, T1 and T3	0.65 v (0.5 v Minimum)	Tune T2 and then T1 for a maximum meter reading. Then tune T3 for minimum meter reading (not required unless changing frequency).
1.	C (AMPL-3)	Pin 3	T4, T3 and T5	0.6 v (0.5 v Minimum)	Tune T4 and then T3 for a maximum meter reading. Then tune T5 for minimum meter reading (not required unless changing frequency).
			М	ULT-3, IPA AN	ND POWER AMPLIFIER
5.	D (MULT-3)	Pin 4	MULT-3 GRID (Z101/Z102)	0.6 v (0.5 v Minimum)	Tune MULT-3 GRID for maximum meter reading.
6.	C (AMPL-3)	Pin 3	T4	Maximum	Retune T4 for maximum meter reading.
7.	D (MULT-3)	Pin 4	MULT-3 GRID (Z101/Z102)	Maximum	Retune MULT-3 GRID for maximum meter reading.
8.	E (MULT-4)	Pin 5	C104 & C115	Maximum	Tune IPA GRID (C104) for maximum meter reading. Then tune C115 for maximum meter reading (not required unless changing frequency).
9.	E (MULT-4)	Pin 5	C121 & C122	See Pro- cedure	Tune C121 clockwise until meter reading drops abruptly. Then turn C122 clockwise for a change in meter reading. This step is not required unless changing frequency.
).	F PA GRID	Pin 14 (+) Pin 6 (-)	AMPL GRID (C130) & C115, C121 & C122	See Pro- cedure	Tune AMPL GRID for maximum meter reading. Then retune C115, C121, C122, and AMPL GRID in that order until no further increase in meter reading is noted.
1.	G PA PLATE	WARN High B+ on Pin 1 (+) Pin 9 (-)		Minimum	Tune AMPL PLATE for a dip in meter reading (not required unless changing frequency).
2.	H REL PWR OUT	Pin 11	OUTPUT TUNING -1 & -2 and AMPL PLATE	Maximum	Alternately tune OUTPUT TUNING -1 and -2 and AMPL PLATE in that order for maximum meter reading.
3.	G PA PLATE	Pin 1 (+) Pin 9 (-)	OUTPUT CONTROL (R124)	See Pro- cedure	Adjust OUTPUT CONTROL for a meter reading of 0.7 volt (0.6 volt for continuous duty stations). - NOTE - Refer to REDUCED POWER OPERATION.
4.					Repeat Steps 12, 13 and 10 in that order



INPU'

TRANSMITTER ALIGNMENT (CONT'D)

STEP	METERI 4EX3A10	NG POSITION Multimeter - at J102	TUNING CONTROL	TYPICAL METER READING	PROCEDURE
			FOR MU	LTI-FREQUENCY	UNITS ONLY
15.	F PA GRID	Pin 14 (+) Pin 6 (-)	AMPL GRID (C130)	See Pro- cedure	After completing Steps 1 thru 14 using the lowest channel frequency, alternately switch from the highest to the lowest frequency and tune AMPL GRID for equal meter readings.
16.	H REL PWR OUT	Pin 11	OUTPUT TUNING-1 and AMPL PLATE	See Pro- cedure	Alternately switch from the highest to the lowest frequency and tune OUTPUT TUNING-1 and AMPL PLATE for equal meter readings.

FREQUENCY ADJUSTMENT

First, check the transmitter frequency to determine if any adjustment is required. The frequency should be checked with a frequency meter or counter having an accuracy of 0.4 partper-million (PPM), and with the ICOM module at 80°F (±4°F) or 26.5°C (±2°C) when possible. The ICOM temperature can be determined by taping a mercury thermometer to the side of the

CAUTION -

The ICOM case is at -20 volts DC. Be careful not to short the case to ground.

If an adjustment is required, use one of the following pro-

If the ICOM is stabilized at 80° F, pry off the GE emblem and adjust the ICOM trimmer for correct transmitter operating. frequency.

If the ICOM is not stabilized at 80° F, pry off the GE emblem and check for a color dot on the top of the can. This color dot indicates which correction curve to use in setting the unit on frequency (see Figure 5). Next, tape a thermometer to the ICOM and check the temperature when the thermometer is stabilized. Then proceed as shown in the following example:

- 1. Assume that the ICOM is marked with a green color dot and the temperature reading is 50° F. At that temperature, the green curve shows a correction factor of approximately +1.5 PPM. (At 450 MHz, 1 PPM is 450 Hz. At 470 MHz, 1 PPM is 470 Hz.)
- 2. With a transmitter operating frequency of 450 MHz, adjust the ICOM trimmer for a reading of +675 Hz (+1.5 x 450) higher than the licensed operating frequency.
- 3. If a negative correction factor is obtained (at temperatures above 80° F), adjust the ICOM trimmer for the indicated PPM lower than the operating frequency.

DEGREES CENTIGRADE

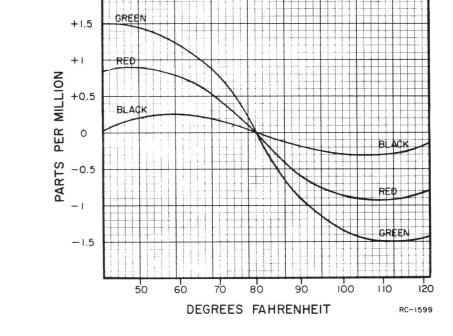


Figure 5 - ICOM Frequency Correction Curves

REDUCED POWER OPERATION

In some services, FCC regulations do not permit the use of full rated power input to the PA Plate circuit. In such cases:

LBI-4000

- 1. In station applications, make sure that the power transformer taps are set for the PA Plate voltage shown in the Maintenance Manual for Power Supply Model 4EP38A10.
- 2. In mobile applications, make sure that the transformer taps are set as shown in the Maintenance Manual for the 4EP37A10, 4EP37B10, 4EP37C10 or
- 3. Adjust the OUTPUT CONTROL for the meter reading shown in the following chart.

		XMTR TYPE	MEASURED PLATE VOLTAGE	METER READING
	For 60-Watt Input	ET-59-C	275 to 305 VDC (see Note 1)	0.7 VDC
	For 30-Watt Input	ET-59-F	275 to 305 VDC (see Note 1)	0.35 VDC
-	For 120-Watt Input	ET-60-C	460 to 510 VDC (see Note 2)	0.7 VDC MAX.

NOTE 1 - If the plate voltage is not within the 275 to 305volt limit, find the OUTPUT CONTROL setting by dividing 210 by the measured plate voltage.

Meter reading in volts = $\frac{210}{\text{Measured Plate Voltage}}$

NOTE 2 - If the Plate Voltage is not within the 460 to 510volt limit, find the OUTPUT CONTROL setting by dividing 311 by the measured plate voltage.

Meter reading in volts = $\frac{311}{\text{Measured Plate Voltage}}$

ALIGNMENT PROCEDURE

406—470 MHz, 35 & 70-WATT TRANSMI**T**TER MODELS 4ET59C30-41, 4ET59F10-13 & 4ET60C30-41

Issue 4

LBI-4000

TEST PROCEDURES

These Test Procedures are designed to assist you in servicing a transmitter that is operating—but not properly. Problems encountered could be low power output, low B plus, tone and voice deviation, defective audio sensitivity and modulator adjust control set too high. By following the sequence of test steps starting with Step 1, the defect can be

quickly localized. Once a defect is pin-pointed, refer to the "Service Check" and the additional corrective measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitter Test Procedures, be sure the transmitter is tuned and aligned to the proper operating frequency.

TEST EQUIPMENT REQUIRED

for test hookup as shown:

1. Wattmeter similar to: 2. VTVM similar to: 3. Audio Generator similar to: 4. Deviation Meter similar to:

Bird #43 Jones #711N

Triplett #850 Heath #IM-21 GE Model 4EX6A10 or Heath #1G-72

Measurements #140

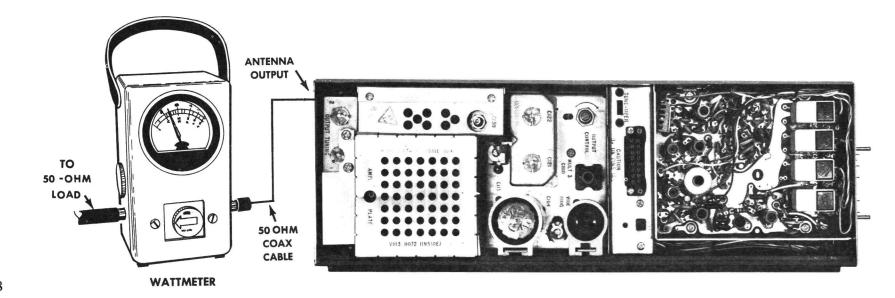
5. Multimeter similar to:

GE METERING TEST SET MODELS 4EX3A10, 4EX8K10 or Triplett #631 or 20,000 ohms-per-volt voltmeter

STEP 1

POWER MEASUREMENT TEST PROCEDURE

1. Connect transmitter output to wattmeter as shown below, using a low-loss coaxial cable between the antenna jack and wattmeter. RG-303/U is recommended for accurate power output readings.



2. Key transmitter and check wattmeter for minimum reading as shown in power output chart on Transmitter Schematic Diagram.

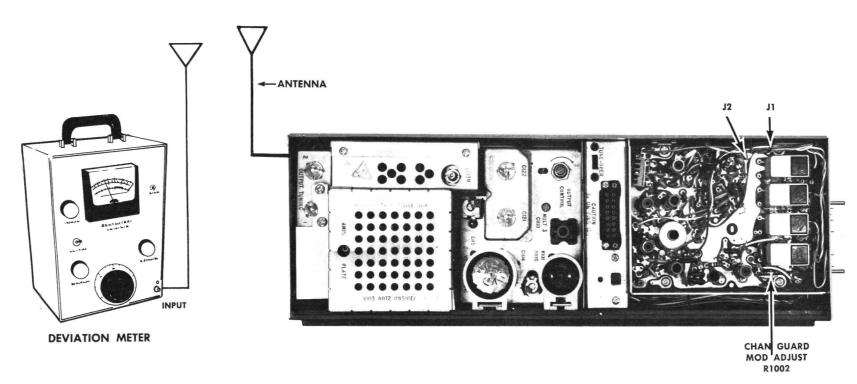
SERVICE CHECK

Refer to Service Hints on Transmitter Troubleshooting Procedure.

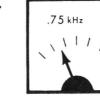
STEP 2

TONE DEVIATION WITH CHANNEL GUARD TEST PROCEDURE

1. Setup Deviation Meter and monitor output of transmitter as shown below:



- 2. Unplug the MIC HI terminal from Jl on Transmitter Exciter Board.
- 3. Key transmitter and check for 0.75 kHz deviation (1.5 kHz wideband). If reading is low or high, adjust Channel Guard MOD ADJUST (R1002) for a reading of 0.75 kHz (1.5 kHz wide-band).



DEVIATION METER

NOTES:

- 1. The Channel Guard MOD ADJUST (R1002) may be adjusted for deviations up to 1 kHz (narrow-band) or 3 kHz (wide-band) for Channel Guard frequencies.
- 2. The Tone Deviation Test Procedures should be repeated everytime the Tone Frequency is changed.

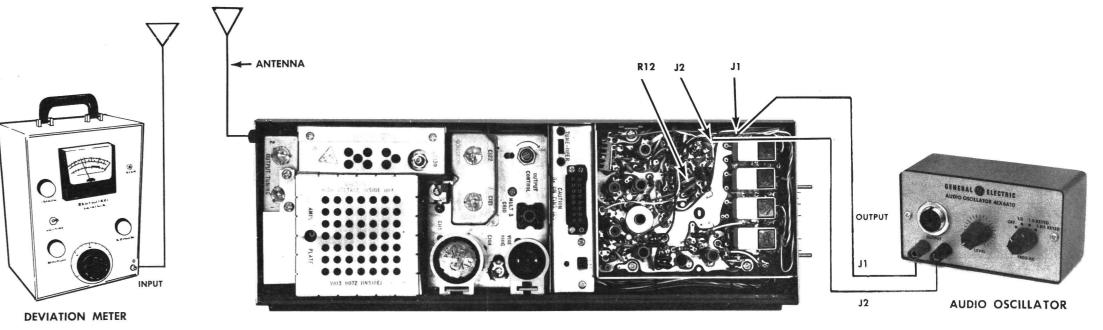
SERVICE CHECK

If the 0.75 kHz (1.5 kHz wide-band) deviation is not obtainable when adjusting R1002, replace the encoder tone network.

STEP 3

VOICE DEVIATION AND SYMMETRY TEST PROCEDURE

- 1. Unplug the High and Low Mike leads from the Exciter Board Jacks Jl and J2.
- 2. Connect test equipment to transmitter as shown below:



- 3. Set the generator output to 0.75 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- 5. Deviation reading should be ± 4.5 kHz (± 13 kHz wide-band).
- 6. Adjust "Modulation Adjust Control" R12 until deviation reads 4.5 kHz (13 kHz wide-band) on plus (+) or minus (-) deviation, whichever is greater. This adjustment should be made with the correct level of tone applied on Channel Guard transmitters.

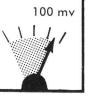


NOTES: MASTR transmitters are adjusted for 4.5 kHz (13 kHz wide-band) deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5 kHz (15 kHz wide-band) under the worst conditions of frequency, voltage and temperature.

If the deviation reading plus (+) and minus (-) differs by more than 0.5 kHz (1.5 kHz wide-band) check the following:

- 1. Recheck Step 1 as shown in the Transmitter Alignment Chart.
- 2. Check Audio Sensitivity by reducing generator output until deviation falls to 3.0 kHz (10 kHz wide-band).





- 8

STEP I - QUICK CHECKS

POWER DUTPUT		CHE		Multimet	er = pin t = A-G	numbers		PROBABLE DEFECT
	Pins 10 & 16 A	Pins 2 & 16 B	Pins 3 & 16 C	Pins 4 & 16 D	Pins 5 & 16 E	Pins 6 & 14 F	Pins 1 & 9 G	
0	0	0	0	0.18 v	0.28 v	0	Low	Defective Q3, Q4 or Modu- lator (see Note A)
0	over 1.0 v	0	0	0.18 v	0.28 v	0	Low	Shorted Q4 or open Q3
0	NORMAL	0 or over 1.0 v	0	0.18 v	0.28 v	0	Low	Defective Q5
0	NORMAL	NORMAL	0 or over 1.0 v	0.18 v	0.28 v	0	Low	Defective Q6
0	NORMAL	NORMAL	Low	0.18 v	0.28 v	0	Low	Open filament on 8106, open coax, bad Q6
0	NORMAL	NORMAL	NORMAL	NORMAL	0.28 v	0	Low	Open filament on 8156
0	NORMAL	NORMAL	NORMAL	NORMAL	NORMAL	0	0	Open filament on 8072
0	NORMAL	NORMAL	NORMAL	NORMAL	0.5 v	0	0	If no peak at position "E" when tuning Cl15, bad multiplier diode or 8156
0	NORMAL	NORMAL	NORMAL	NORMAL	NORMAL	High	Very Low or 0	Bad R123/R126, bad R124, shorted 8072 screen
Low	NORMAL	NORMAL	NORMAL	NORMAL	NORMAL	Low	0.70 v	Weak 8156 or 8072
Erra- tic	NORMAL	NORMAL	NORMAL	NORMAL	NORMAL	Very High	0.70 v	Check contacts on screen by-pass ring
NOTE:	Localize	trouble	by check	ing:				
		supply a						
								ns), then;
(a)	resisto	oltage is rs R19, I keyed and	21, R23,	and R25	. Volta	leads by ge shoul	measuri ld read l	ing the voltage drop across 10 voltage when that chan-
(b)		a indica	ites 10 v	olts and	l no volt	age is m	neasured	across R28, suspect bad
(c)	at mete	OMs remover position	on A indi	cates Q3	e to emi and Q4	tter. A		e reading above 1.0 volts ading remains zero, check

(d) If Step C is normal, defect is in modulator. Check voltage variable diode CV1.

- 75 - 78.3 MHz 67.6 - 70 MHz __ 450-470 MHz_ 406-420 MHz _ 12.5-13.033 MHz _ 11.3-11.67 MHz 37.5 - 39.1 MHz __ 33.8 - 35 MHz VIO3 8072 PA **Q6** AMPL-3. RI2 MOD ADJ 2.5 V } 1.2V R36 0.9 V I V STEP 2 CHECK TYPICAL DC VOLTAGES

EQUIPMENT REQUIRED

G.E. TEST MODEL 4EX3AIO 300 V - 20 VDC SUPPLY ● 20,000 OHM-PER-VOLT METER STEP 3
CHECK AUDIO AC VOLTAGES VTVM-AC EQUIPMENT REQUIRED

AUDIO OSCILLATOR

AC VTVM J102-14 -20 V ← + SET AUDIO OSCILLATOR 5.2 VAC | 0.19 VAC | 1.7 VAC | 0.34 VAC J102-16 J102-16 J102-16 STEP 5
COMPONENT VOLTAGE CHECKS

EQUIPMENT REQUIRED

GE TEST SET MODEL 4EX3AIO
OR

20,000 OHM-PER-VOLT DC METER AT 1000 Hz WITH OUTPUT OF .75 V. RMS. V-DC V-DC STEP 4

AUDIO & OSC. WAVEFORMS

EQUIPMENT REQUIRED

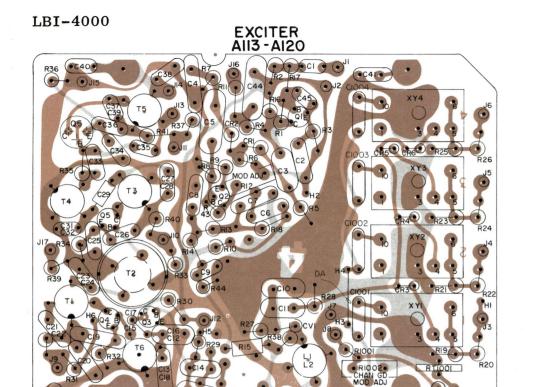
AUDIO OSCILLATOR

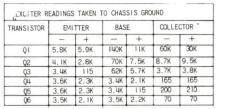
OSCILLOSCOPE WITH TRANSMITTER
KEYED, READING AT
JIO2-1 (PA PLATE)
SHOULD BE APPROX
O.7 VDC
CAUTION: HIGH VOLTAGE
ON TEST LEADS WITH TRANSMITTER KEYED, READING AT JIO2-3 (AMPL-3) SHOULD BE APPROX O.7 VDC (0.5 VDC MIN) WITH TRANSMITTER KEYED, READING AT JIO2-11 INDICATES RELATIVE POWER OUTPUT (TUNED FOR MAX. WITH TRANSMITTER KEYED, READING AT JIO2-4 (MULT-3) SHOULD BE APPROX O.7 VDC (0.50 VDC MIN) WITH TRANSMITTER KEYED, READING AT JIO2-5 (MULT-4) SHOULD BE APPROX O.7 VDC (0.50 VDC MIN) WITH TRANSMITTER
KEYED, READING AT
JIO2-6 (PA GRID)
SHOULD BE APPROX
O.5 VDC
(0.2 VDC MIN) WITH TRANSMITTER
KEYED, READING AT
JIO2-IO (MULT-I)
SHOULD BE APPROX
O.7 VDC
(0.5 VDC MIN) WITH TRANSMITTER
KEYED, READING AT
JIO2-2 (MULT-2)
SHOULD BE APPROX
O.7 VDC
(0.5 VDC MIN) NOTE-READING WILL VARY WITH LOAD IMPEDANCE. 50 MV/DIV SET AUDIO OSCILLATOR AT 1000 Hz WITH OUTPUT OF .75 V. RMS. RC-1595

TROUBLESHOOTING PROCEDURE

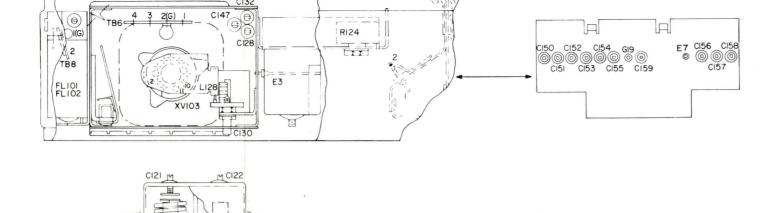
406-470 MHz, 35 & 70-WATT TRANSMITTER MODELS 4ET59C30-41, 4ET59F10-13 & 4ET60C30-41

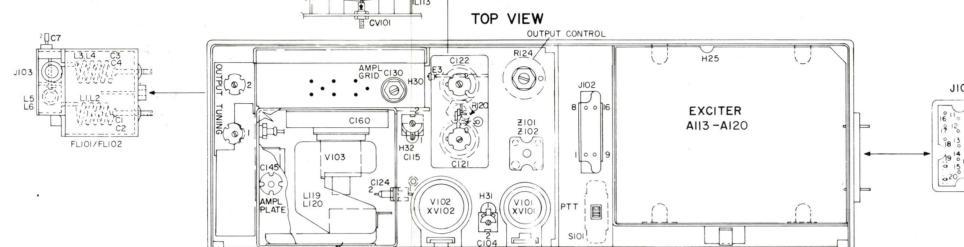
Issue 1

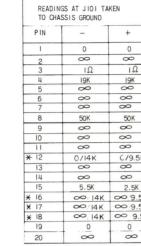




EXCITER READIN	IGS TAK	EN TO 2	O VOLT	LINE (J	15 BLUE	LEAD)
TRANSISTOR	EMITTER		BASE		COLLECTOR	
	-	+	1-1	+		+
QI	9.5K	IOK	145K	17.2K	63K	45K
02	450	450	68K	3.5K	11.5K	13.5K
Q3	0	0	68K	3.2K	7K	8K
Q4	13	120	0	0	2.2K	3.7K
Q5	54	120	0	0	- 52	3.7K
Q6	22	25	47	45	2.2K	3.5K





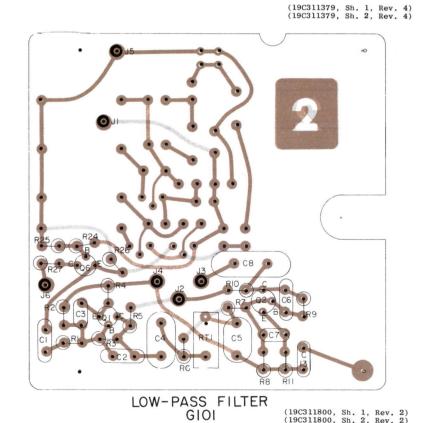


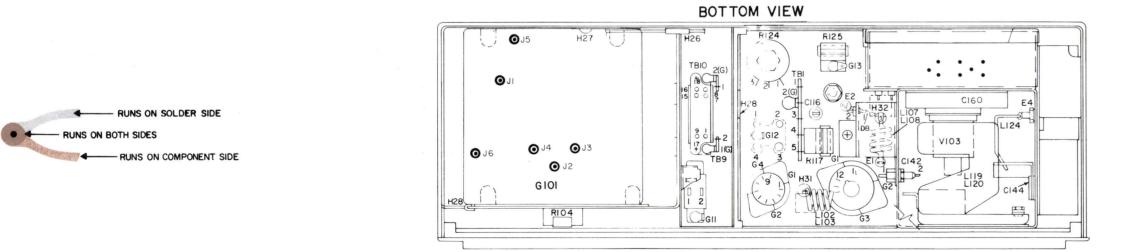
* IST READING FOR SINGLE FREQ. 2ND READING FOR MULTI-FREQ.

RESISTANCE READINGS

READINGS ARE TYPICAL READINGS MEASURED

1 A 20,000 OHM-PER-VOLT METER AND JIDI
ONNECTED. + OR - SIGNS SHOW METER
D. GROUNDED. OUTPUT CONTROL FULLY COUNTER-





SIDE VIEW

EAUTNGS	TAKEN FROM	I TUDE SOUN	ET PINS TO CHA	issis unuu	NU							
IN	Ī	2	3	4	5	6	7	8	9	10	- 11	12
101	20K	0	46K	1Ω	0	0	32K	46K	0			
102	1	0	19K	19K	19K	0	24K	0	0	55K	24K	0
103	0	000	2K/6K *	0	0	IΩ	12.5K	2K 6K *	0		2K 6K *	

* READING DEPENDS ON METER POLARITY.

OUTLINE DIAGRAM

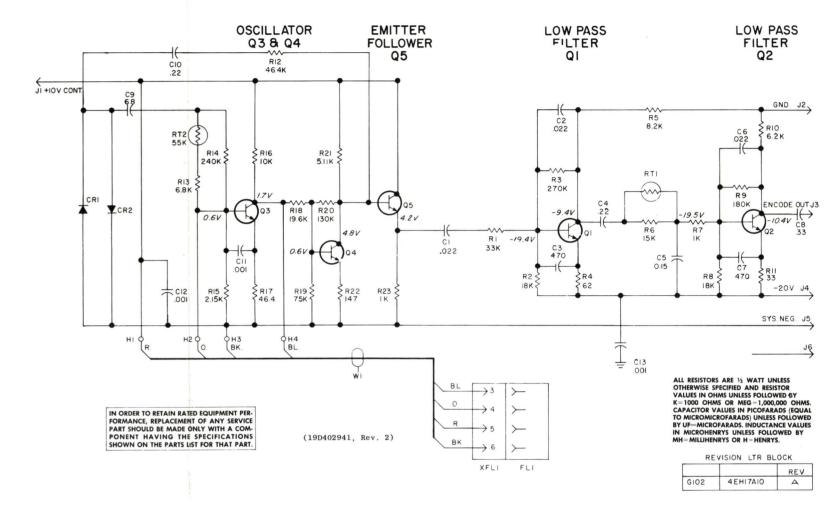
406-470 MHz, 35 & 70-WATT TRANSMITTER MODELS 4ET59C30-41, 4ET59F10-13 & 4ET60C30-41

.0 Issue 5

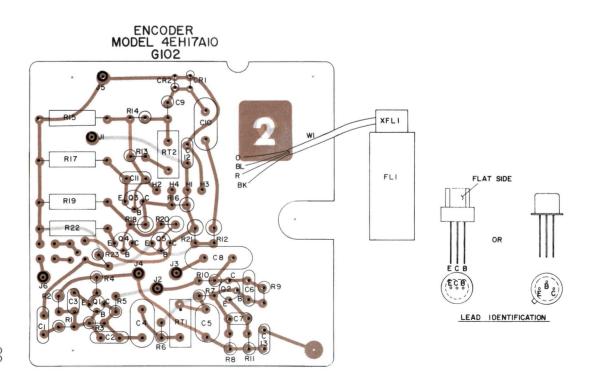
(19R621287, Rev. 5)

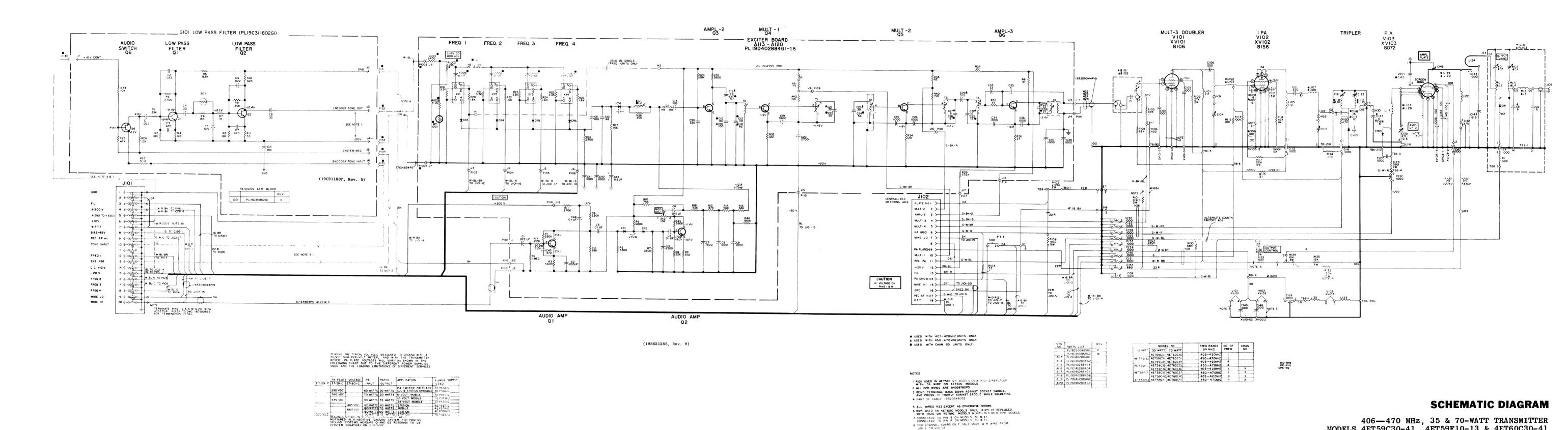
CHANNEL GUARD ENCODER MODEL 4EH17A10

SCHEMATIC DIAGRAM



OUTLINE DIAGRAM





5 ALL WIRES N22 EXCEPT AS OTHERWISE SHOWN.

6.RI23 USED IN 4ET50C MODELS ONLY, RI23 IS REPLACED WITH RI26 ON 4ET59C MODELS 8 WITH RI31 ON 4ET59F MODELS.

7. CONNECTED TO PIN 6 ON MODELS 36 8 37.
CONNECTED TO PIN 14 ON MODELS 40 8 41.

8 FOR CHANNEL GUARD ON F. CALLY MOVE W. R. WIRE FROM JUN-6 TO JUN-14.

9. RI32 USED IN 4ET59F MODELS ONLY

SCHEMATIC DIAGRAM

406-470 MHz, 35 & 70-WATT TRANSMITTER MODELS 4ET59C30-41, 4ET59F10-13 & 4ET60C30-41

Issue 7

PARTS LIST

LBI-4024F

406-470 MHz TRANSMITTERS
(WITH ICOM)
MODELS 4ET59C30, 34, 36, 40 (19E500865G1)
MODELS 4ET59C31, 35, 37, 41 (19E500865G2)

All3 19hO2884G1 4FT90C30, 4FT90C30 All4 19hO2884G2 4FT90C30, 4FT90C31, 4F All5 19hO2884G3 4FT90C34, 4FT60C31, 4F All5 19hO2884G3 4FT90C34, 4FT60C31, 4F All6 19hO2884G3 4FT90C34, 4FT60C35, 4F All7 19hO2884G3 4FT90C36, 4FT60C35, 4F All7 19hO2884G3 4FT90C36, 4FT60C37, 4F All7 19hO2884G3 4FT90C41, 4FT60C41, 4F
C1 194116080P3 Polyester: 0.022 µf ±20%, 50 VDCW. C2 194116080P4 Polyester: 0.033 µf ±20%, 50 VDCW. C3 194116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sin MMC Type JL. C5 194116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 194116080P5 Polyester: 0.047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sin RMC Type JL. C8 3nd RMC Type JL. C8 7491395P109 Ceramic disc: 1500 pf ±10%, 500 VDCW; sin RMC Type JL. C8 7493366P100J Mica: 1500 pf ±5%, 500 VDCW, temp of 150 PPM. C11 5493366P100J Mica: 150 pf ±5%, 100 VDCW; sim to Electric Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electric Motive Type DM-15. C13 5496219P564 Ceramic disc: 110 pf ±5%, 500 VDCW, temp of 159366P180K Mica: 180 pf ±10%, 100 VDCW; sim to Electric Motive Type DM-15. C15 5491601P24 Phenolic: 1.8 pf ±10%, 500 VDCW; sim to Electric Motive Type DM-15. C16 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electric Motive Type DM-15. C17 5491601P32 Phenolic: 1.8 pf ±10%, 500 VDCW; sim to Electric Motive Type DM-15. C18 5496219P561 Ceramic disc: 100 pf ±5%, 500 VDCW; sim to Electric Motive Type DM-15. C19 5494481P129 Ceramic disc: 82 pf ±5%, 500 VDCW; sim to Electric Motive Type DM-15. C20 5494481P128 Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim MC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of 80 PPM. C22 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of 80 PPM. C23 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of 80 PPM. C24 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of 80 PPM. C25 5496481P111 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of 80 PPM. C26 5496481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim MC Type JF Discap. C27 5496219P400 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp of 80 PPM.
C2 194116080P4 Polyester: 0.033 µf ±20%, 50 VDCW. C3 194116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Cramic disc: 2200 pf ±10%, 500 VDCW; sin RMC Type JL. C5 194116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 194116080P5 Polyester: 0.047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sin RMC Type JL. C8 7491395P109 Ceramic disc: 1500 pf ±10%, 500 VDCW; sin RMC Type JL. C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW; sin RMC Type DM-15. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electric Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electric Motive Type DM-15. C13 5496219P564 Ceramic disc: 110 pf ±5%, 500 VDCW, temp c-330 PPM. C14 593366P180K Mica: 180 pf ±10%, 100 VDCW; sim to Electric Motive Type DM-15. C15 5491601P24 Phenolic: 1.8 pf ±10%, 500 VDCW; sim to Components Type MC. C16 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electric Motive Type DM-15. C17 5491601P32 Phenolic: 4.7 pf ±10%, 500 VDCW; sim to Components Type MC. C18 5496219P561 Ceramic disc: 82 pf ±5%, 500 VDCW; sim Motive Type DM-15. C19 5494481P129 Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C20 5494481P128 Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp c-80 PPM. C22 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp c-80 PPM. C23 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c-80 PPM. C24 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp c-80 PPM. C25 5494481P11 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c-80 PPM. C26 5494481P11 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c-80 PPM. C27 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c-80 PPM. C28 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c-80 PPM. C29 5496219P257 Ceramic disc: 500 pf ±0%, 1000 VDCW; sin MC Type JF Discap. C27 5496219P257 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp c-80 PPM.
C3
Ceramic disc: 2200 pf ±10%, 500 VDCW; sin MRC Type JL. C5
C6
C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sin RMC Type JL. C8 and C9 C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp c150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electromotive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electromotive Type DM-15. C13 5496219P564 Ceramic disc: 110 pf ±5%, 500 VDCW, temp c130 PPM. C14 593366P180K Mica: 180 pf ±10%, 100 VDCW; sim to Electromotive Type DM-15. C15 5491601P24 Phenolic: 1.8 pf ±10%, 500 VDCW; sim to Electromotive Type DM-15. C16 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electromotive Type DM-15. C17 5491601P32 Phenolic: 1.8 pf ±10%, 500 VDCW; sim to Electromotive Type DM-15. C18 5496219P561 Ceramic disc: 82 pf ±5%, 500 VDCW; sim to Electromotive Type MC. C18 5496219P561 Ceramic disc: 82 pf ±5%, 500 VDCW; sim to Electromotive Type MC. C19 5494481P129 Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim MC Type JF Discap. C20 5494481P128 Ceramic disc: 39 pf ±5%, 500 VDCW, temp c1 -80 PPM. C21 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp c1 -80 PPM. C22 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C26 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c1 -80 PPM. C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
RMC Type JL. Ceramic disc: 1000 pf ±10%, 500 VDCW; sin RMC Type JL.
C8 and C9 C10 C10 C10 C10 C10 C10 C11 C11 C11 C11
C10 5496219P359
Motive Type DM-15.
Motive Type DM-15.
-330 PPM. C14 593366P180K Mica: 180 pf ±10%, 100 VDCW; sim to Elect Motive Type DM-15. C15 5491601P24 Phenolic: 1.8 pf ±10%, 500 VDCW; sim to Components Type MC. C16 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Components Type MC. C17 5491601P32 Phenolic: 4.7 pf ±10%, 500 VDCW; sim to Components Type MC. C18 5496219P561 Ceramic disc: 82 pf ±5%, 500 VDCW, temp of -330 PPM. C19 5494481P129 Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C20 5494481P128 Ceramic disc: 2700 pf ±10%, 1000 VDCW; sim RMC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C22 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C23 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C24 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5494481P111 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C26 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C27 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C28 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C29 5496219P259 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C29 5496219P259 Ceramic disc: 90 pf ±0.25 pf, 500 VDCW; sign of the total content o
Motive Type DM-15.
Components Type MC. C16 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electromotive Type DM-15. C17 5491601P32 Phenolic: 4.7 pf ±10%, 500 VDCW; sim to Components Type MC. C18 5496219P561 Ceramic disc: 82 pf ±5%, 500 VDCW, temp of -330 PPM. C19 5494481P129 Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim RMC Type JF Discap. C20 5494481P128 Ceramic disc: 2700 pf ±10%, 1000 VDCW; sim RMC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C22 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C23 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C24 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5494481P111 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5494481P111 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5496219P240 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sign RMC Type JF Discap. C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
Motive Type DM-15.
Components Type MC. C18 5496219P561 Ceramic disc: 82 pf ±5%, 500 VDCW, temp of -330 PPM. C19 5494481P129 Ceramic disc: 3900 pf ±20%, 1000 VDCW; si RMC Type JF Discap. C20 5494481P128 Ceramic disc: 2700 pf ±10%, 1000 VDCW; si RMC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C22 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C23 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C24 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C26 5494481P111 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C27 5496219P440 Ceramic disc: 9.0 pf ±20%, 1000 VDCW; si RMC Type JF Discap.
-330 PPM. C19 5494481P129 Ceramic disc: 3900 pf ±20%, 1000 VDCW; si RMC Type JF Discap. C20 5494481P128 Ceramic disc: 2700 pf ±10%, 1000 VDCW; si RMC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C22 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C23 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C24 5496219P257 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5496219P257 Ceramic disc: 1000 pf ±20%, 1000 VDCW; si RMC Type JF Discap. C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
RMC Type JF Discap. C20 5494481P128 Ceramic disc: 2700 pf ±10%, 1000 VDCW; si RMC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp control to the second
RMC Type JF Discap. C21 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C22 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C23 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C24 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5494481P111 Ceramic disc: 56 pf ±20%, 1000 VDCW; signed and C26 C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
-80 PPM. C22 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C23 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C24 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C25 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; signed C26 C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
-80 PPM. C23 5496219P253 Ceramic disc: 39 pf ±5%, 500 VDCW, temp of -80 PPM. C24 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp of -80 PPM. C25 and C26 C27 5496219P440 Ceramic disc: 1000 pf ±20%, 1000 VDCW; si RMC Type JF Discap. C26 C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
-80 PPM. C24 5496219P257 Ceramic disc: 56 pf ±5%, 500 VDCW, temp c -80 PPM. C25 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; si RMC Type JF Discap. C26 C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
-80 PPM. C25
and C26 RMC Type JF Discap. C27 5496219P440 Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW,
coef -220 PPM.
C28 5496219P343 Ceramic disc: 13 pf ±5%, 500 VDCW, temp c
C29 5491601P35 Phenolic: 0.15 pf ±10%, 500 VDCW; sim to Components Type MC.

SYMBOL	GE PART NO.	DESCRIPTION	SYMBO
C30	5493366P330K	Mica: 330 pf ±10%, 100 VDCW; sim to Electro	R11
C31	5496219 P2 41	Motive Type DM-15. Ceramic disc: 10 pf ±5%, 500 VDCW, temp coef	R12
C32	5496219P244	-80 PPM. Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef	R13
C33	5496219P51	-80 PPM. Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef	R14
		O PPM.	R15 and R16
C34	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R17
C35	5496219P35	Ceramic disc: 4.0 pf ±5%, 500 VDCW, temp coef 0 PPM.	R18
C36	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R19 R20
C37	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -80 PPM.	R21
C38	5494481P111	Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R22
C39	5496219P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef	R23 R24
C40	5494481P111	-80 PPM. Ceramic disc: .001 pf ±20%, 1000 VDCW; sim to	R25
thru C42		RMC Type JF Discap.	R26
C43	5496267P18	Tantalum: 6.8 μf ±20%, 35 VDCW; sim to Sprague Type 150D.	R27 R28
C44	19A115414P13	Polyester: 0.1 μf ±20%, 200 VDCW.	R29
C45	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R30
		DIODES AND RECTIFIERS	R31
CR1	19All5331Pl	Silicon.	R32 R33
and CR2			R34
CR3 thru	19A115250P1	Silicon.	R35
CR6 CV1	5495769P8	Silicon, capacitive.	R36 R37
			R38
J1	4033513P4	JACKS AND RECEPTACLES Contact, electrical; sim to Bead Chain L93-3.	R39
thru J17		,	R40
			R41 R42
L1 L2	19B204526G2 19B204526G1	Coil Includes tuning slug 5491798P2.	R43
LZ	19820432001	Coil. Includes tuning slug 5491798P2.	. R44
Q1	19A115123P1	TRANSISTORS	
and Q2	19411312371	Silicon, NPN; Sim to Type 2N2712.	Tl
Q3	19A115330Pl	Silicon, NPN.	T2
Q4 and	19A115328P1	Silicon, NPN.	T3
Q5 Q6	19A115329Pl	Silian NDN	т5
Q O	19411332971	Silicon, NPN.	т6
R1	3R77P334K		
R2	3R77P105K	Composition: 1 megohm ±10%, 1/2 w.	XY1 thru
R3	3R77P562K	Composition: 5600 ohms ±10%, 1/2 w.	XY4
R4	3R77P224K	Composition: 0.22 megohm ±10%, 1/2 w.	
R5	3R77P334K	Composition: 0.33 megohm ±10%, 1/2 w.	
R6	3R77P684K	Composition: 0.68 megohm $\pm 10\%$, $1/2$ w.	
R7	3R77P334K	Composition: 0.33 megohm ±10%, 1/2 w.	
R 8	3R77P823K	Composition: 82,000 ohms ±10%, 1/2 w.	Y1
R9	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	thru Y4
R10	3R77P753J	Composition: 75,000 ohms ±5%, 1/2 w.	

	SYMBOL	G-E PART NO	DESCRIPTION
Electro	Rll	3R77P274K	Composition: 0.27 megohm ±10%, 1/2 w.
temp coef	R12	19B209358P106	Variable, carbon film: approx 75 to 10,000 ohms $\pm 10\%$, 0.25 w; sim to CTS Type X-201.
temp coef	R13	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.
temp coef	R14 R15	3R77P563K 3R77P683K	Composition: 56,000 ohms ±10%, 1/2 w. Composition: 68,000 ohms ±10%, 1/2 w.
CW; sim to	and R16		
temp coef	R17 R18	3R77P222K 3R77P433J	Composition: 2200 ohms ±10%, 1/2 w. Composition: 43,000 ohms ±5%, 1/2 w.
	R19	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.
CW; sim to	R20	3R77P162J	Composition: 1600 ohms ±5%, 1/2 w.
temp coef	R21	3R77P332J	Comosition: 3300 ohms ±5%, 1/2 w.
	R22	3R77P162J	Composition: 1600 ohms ±5%, 1/2 w.
CW; sim to	R23	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.
temp coef	R24	3R77P162J	Composition: 1600 ohms ±5%, 1/2 w.
-	R25	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.
CW; sim to	R26	3R77P162J	• • • • • • • • • • • • • • • • • • • •
	R27	3R77P102S	Composition: 1600 ohms ±5%, 1/2 w. Composition: 10,000 ohms ±10%, 1/2 w.
to Sprague	R28		, , , , , , , , , , , , , , , , , , , ,
	1	3R77P272K	Composition: 2700 ohms ±10%, 1/2 w.
	R29	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.
N; sim to	R30	3R77P392K	Composition: 3900 ohms ±10%, 1/2 w.
	R31	3R77P750J	Composition: 75 ohms ±5%, 1/2 w.
	R32	3R77P121J	Composition: 120 ohms ±5%, 1/2 w.
	R33	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.
	R34	3R77P121J	Composition: 120 ohms ±5%, 1/2 w.
	R35	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.
	R36	3R77P270K	Composition: 27 ohms ±10%, 1/2 w.
	R37	3R77P200J	Composition: 20 ohms ±5%, 1/2 w.
1	R38	3R77P363J	Composition: 36,000 ohms ±5%, 1/2 w.
1 102 2	R39	19A116278P474	Metal film: 0.576 megohm ±2%, 1/2 w.
in L93-3.	R40	3R77P151K	Composition: 150 ohms ±10%, 1/2 w.
	R41	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.
	R42	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.
2.	R43	3R77P364J	Composition: 0.36 megohm ±5%, 1/2 w.
2.	R44	3R77P184K	Composition: 0.18 megohm ±10%, 1/2 w.
			,
	Tl	10000452461	TRANSFORMERS
	T1	19B204534G1	Coil Includes tuning slug 5491798P4.
	1	19B204531G2	Coil. Includes tuning slug 5491798P4.
	T3	19B204535G1 19B204535G2	Coil. Includes tuning slug 5491798P4.
	1		Coil. Includes tuning slug 5491798P4.
1	T5	19B204537G1	Coil. Includes tuning slug 5491798P4.
	Т6	19B216035G1	Coil. Includes tuning slug 5491798P4.
			SOCKETS
w.	XY1	19B216043G1	Socket assembly. Includes:
i	thru XY4		••
		19D413071P1	Socket cavity.
w.		19A115834P2	Contact, electrical: sim to AMP 380598-2.
w.			OSCILLATORS
w.		1	
w.			When reordering, specify ICOM Frequency. ICOM Frequency = operating frequency
w.	Y1	4EG25A10	Intermeted Cinemia Continue William Continue
	thru Y4	AEGEONIO	Integrated Circuit Oscillator Module (ICOM).
· .	14	19D413070P1	Cap, decorative.
	1		
		l	

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMB
		CHANNEL GUARD MODIFICATION KIT 19A127078G1	C138	7489162P27	Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
		(Used with Al17-Al20)	C140	7489162P27	Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	J1 thr
	10000004000		C142	7485975P17	Ceramic, feed-thru: 470 pf ±20%, 750 VDCW; sim to Erie Style 327.	J6
C1001 thru C1004	19B209243P7	Polyester: 0.1 μf ±20%, 50 VDCW.	C143		Refer to Mechanical Parts (RC-1593), items 10, and 11.	Q1 and
		RESISTORS	C144		Refer to Mechanical Parts (RC-1593), items 21,	Q2 Q6
R1001 R1002	3R77P242J 19B209358P107	Composition: 2400 ohms ±5%, 1/2 w. Variable, carbon film: approx 75 to 25,000 ohms	C145		22, and 31. Refer to Mechanical Parts (RC-1593), items 12	
R1003	3R77P512J	±10%, 0.25 w; sim to CTS Type X-201. Composition: 5100 ohms ±5%, 1/2 w.	C147	5493392P7	thru 16. Ceramic, feed-thru: 1000 pf +100%-0%, 500 VDCW;	Rl
		THERMISTORS	C148	5494481P12	sim to Allen-Bradley Type FA5C. Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to	R2 R3
RT1001	19C300048P8	Disc: 2500 ohms ±10%; sim to GE 4D403.	and C149		RMC Type JF Discap.	R4
			C150 thru	5493392P7	Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.	R5
		CHASSIS 19E500865G1 4ET59C30, 34, 36, 40 4ET60C30, 34, 36, 40	C156 C157	19B209282P1	Ceramic, feed-thru: 680 pf ±20%, 1000 VDCW; sim	R6 R7
		19E500865G2 4ET59C31, 35, 37, 41 4ET60C31, 35, 37, 41	C158	5493392P7	to Sprague Type 544C. Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW;	R8
			and C159		sim to Allen-Bradley Type FA5C.	R9
0101	5494481P12	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C160*	19B209369P2	Mica: 2500 pf ±20%, 400 VDCW; sim to EF Johnson 124-113-18. Added to 19E500865G2 by REV B. Added to 19E500865G1 by REV C.	R1
C104	5491271P6	Variable: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189.				R24
C105	5494481P12	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	CR101	4037822P1	DIODES AND RECTIFIERS Silicon.	R2:
C106	19B209204P1	Ceramic disc: 220 pf ±10%, 500 VDCW, temp coef -4700 PPM.	CV101*	19A115809P2	Silicon, capacitive.	R2
C107	7489162P7	Silver mica: 12 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.			In 19E500865G1 of REV A and earlier: In 19E500865G2 of REV C and earlier:	
C108	7489162P4	Silver mica: 8 pf ±0.5 pf, 500 VDCW; sim to		19A115809P1	Silicon, capacitive.	RT:
C109	7489162P27	Electro Motive Type DM-15. Silver mica: 100 pf ±5%, 500 VDCW; sim to		1000052502		
C110	7489162P31	Electro Motive Type DM-15. Silver mica: 150 pf ±5%, 500 VDCW; sim to	E1 E2	19B200535P3 4029309P1	Feed-thru: sim to Sealectro ST-1500SL-C3. Feed-thru: sim to Sealectro FT-SM-27.	J101
2111	19B209204P1	Electro Motive Type DM-15. Ceramic disc: 220 pf ±10%, 500 VDCW, temp coef	E3	4036032P5	Feed-thru: sim to Sealectro FT-SM-10.	J102
0113	5493392P7	-4700 PPM. Ceramic: 1000 pf +100% -0%, 500 VDCW; sim	E7	4034512P2	Feed-thru: sim to Sealectro FT-SM-22-TUR.	L101
		to Allen-Bradley Type FA5C.			BANDPASS FILTER	L102
0115	19B209372P1	Variable: approx 2.3 to 24.3 pf; sim to EF Johnson Type V 193-0008-010.			NOTE: The bandpass filters are factory tuned. If a filter component (except as shown	L103
C116	5493392P7	Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.			below) is found to be defective, it is recommended that the entire filter	L105
C118	7489162P8	Silver mica: 15 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.			assembly be replaced to maintain rated power output and spurious attenuation.	L107
C119*	7489162P7	Silver mica: 12 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	FL101 FL102	19C303559G1 19C303559G2	406-420 MHz. 450-470 MHz.	L108
	540014054	In REV B and earlier:	G101		LOW PASS FILTER ASSEMBLY	L111
	7489162P6	Silver mica: 10 pf ±0.5 pf, 500 VDCW; sim to Electro Motive Type DM-15.	0101		19C311802G1	L112
C121 and C122		Refer to Mechanical Parts (RC-1593), items 15, 27, 29, and 30.			CAPACITORS	L113
C125	7489162P2	Silver mica: 6 pf ±0.5 pf, 500 VDCW; sim to Electro Motive Type DM-15.	C1 C2	19A116080P103 19A116080P3	Polyester: 0.022 µf ±20%, 50 VDCW. Polyester: 0.022 µf ±20%, 50 VDCW.	L116
C126	7489162P1	Silver mica: 5 pf ±0.5 pf, 500 VDCW; sim to Electro Motive Type DM-15.	СЗ	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	L117
0127	5494481P12	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to	C4	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW.	L119
C128	5493392P7	RMC Type JF Discap. Ceramic, feed-thru: 1000 pf +100%-0%, 500 VDCW;	C5	19A116080P8	Polyester: 0.15 µf ±20%, 50 VDCW.	L120
C130	5490272P17	sim to Allen-Bradley Type FA5C. Variable: 2 to 7.83 pf, 1250 v peak; sim to	C6 C7	19A116080P3 5494481P107	Polyester: .022 µf ±20%, 50 VDCW. Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to	L122
C132	5493392P7	Johnson Type M. Ceramic, feed-thru: 1000 pf +100%-0%, 500 VDCW;	C8	19B209243P14	RMC Type JF Discap. Polyester: 0.33 µf ±20%, 250 VDCW.	L124 L125
C135*	19B209369P1	sim to Allen-Bradley Type FA5C. Mica: 2650 pf ±20%, 400 VDCW; sim to EF Johnson	C13	5494481P111	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	and L126
C133+	198209309F1	124. Deleted in 19E500865G2 by REV B. Deleted in 19E500865G1 by REV C.				
C136	7489162P27	Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.				
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IMBOL	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION
		JACKS AND RECEPTACLES	L127	19B204658P3	Grid line.			
J1	4033513P4	Contact, electrical; sim to Bead Chain L93-3.	L128	19B204658P1	Grid line.	V101		Type 8106.
thru J6		conserved the second single second single second single second single second second second single second se				V102		Type 8156.
		TRANSISTORS		·		V103		Type 8072.
Q1	19A115123P1	Silicon, NPN; sim to Type 2N2712.	P101	4029840P2	Contact, electrical: sim to AMP 42827-2.			
and Q2		,,	P102	4029840P1	Contact, electrical: sim to AMP 41854.	XV101	7480532P8	Tube, phen: 9 pins; sim to Elco 04-903-84.
Q6	19A115123P1	Silicon, NPN; sim to Type 2N2712.	P103 thru P106	4029840P2	Contact, electrical: sim to AMP 42827-2.	XV102	19C301007P5	Tube, plastic: 12 pins; sim to Alcon Metal Products 371G.
Rl	3R77P333K	RESISTORS	P109 thru P113	4029840P2	Contact, electrical: sim to AMP 42827-2.	XV103	19B209160P1	Tube, plastic: ll pins; sim to EF Johnson 124.
R2	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.	P113	4029840Pl	Contact, electrical: sim to AMP 41854.			TUNED CIRCUITS
R3	3R77P274K	Composition: 0.27 megohm ±10%, 1/2 w.	P115	4029840P2	Contact, electrical: sim to AMP 42827-2.	Z101 C1	19B204543G2 5496203P468	Coil. Includes tuning slug 5491798P4. Capacitor, ceramic disc: 510 pf ±5%, 500 VDCW,
R4	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.	thru Pl17	102001012	Survey, electricar. Sim to har 12021-2.		34502037406	temp coef -5600 PPM.
R5	3R77P822K	Composition: 8200 ohms ±10%, 1/2 w.	1		RESISTORS	Z102 C1	19B204543G1 5496203P468	Coil. Includes tuning slug 5491798P4. Capacitor, ceramic disc: 510 pf ±5%, 500 VDCW.
R6	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	R101	19A115416P1	Precision, wirewound: 0.91 ohm ±1%, 2 w; sim	,	04502007400	temp coef -5600 PPM.
R7	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.			to Dale Type RS-2B.			MISCELLANEOUS
R8	3R77P183K	Composition: 18.000 ohms ±10%, 1/2 w.	R102	19A115416P3	Precision, wirewound: 2.59 ohms ±1%, 2 w; sim to Dale Type RS-2B.		19B209044P19	RF Cable: approx 30 inches long, (Located
R9	3R77P184K	Composition: 0.18 megohm ±10%, 1/2 w.	R103	3R77P330J	Composition: 33 ohms ±5%, 1/2 w.		102200011710	between J13 on Exciter Board and Z101-Z102).
R10	3R77P622J	Composition: 6200 ohms ±5%, 1/2 w.	R104	5493035P11	Wirewound: 40 ohms ±5%, 5 w; sim to Tru-Ohm			MECHANICAL PARTS
R11	3R77P330K	Composition: 33 ohms ±10%, 1/2 w.			Туре X-60.			(SEE RC-1593)
R24	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R105	3R77P393J	Composition: 39,000 ohms ±5%, 1/2 w.	1	19C311152P1	Heat sink.
R25	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.	R106	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.	2	7165167P5	Insert, tube shield: sim to Atlas Insert
R26	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R107	19A116278P444	Metal film: 0.28 megohm ±2%, 1/2 w.	-		106-332-5. (Used with V101).
R27	3R77P512K	Composition: 5100 ohms ±10%, 1/2 w.	R108	3R77P683J	Composition: 68,000 ohms $\pm 5\%$, $1/2$ w.	3	19B204570P3	Heat sink. (Used with V101).
			R109	3R79P273K	Composition: 27,000 ohms ±10%, 2 w.	4	19A122497P1	Support. (Used with V101).
			R112	3R77P103J	Composition: 10,000 ohms ±5%, 1/2 w.	5	7165167 P 9	Insert, tube shield: sim to Atlas Insert 106-332-21. (Used with V102).
RT1	5490828P30	Rod: 0.33 megohm ±10% res, 1 w max; sim to Globar Type 783H-3.	R113	3R77P104J	Composition: 0.1 megohm ±5%, 1/2 w.	6	19A122497P2	Support. (Used with V102).
		3,70 1344 51	R114*	3R77P201J	Composition: 200 ohms ±5%, 1/2 w.	7	19A122498P1	Heat sink. (Used with V102),
			1		In 19E500865Gl of REV A and earlier: In 19E500865G2 of REV C and earlier:	8	19C311164P6	Plate line, (Used with L119),
J101	19C303426G1	Connector: 20 pin contacts.	.]	3R77P681J	Composition: 680 ohms $\pm 5\%$, $1/2$ w.	9	19C311164P5	Plate line. (Used with L119).
J102	19B205689G1	Connector: 18 electrical contacts.	R115	3R77P510J	Composition: 51 ohms ±5%, 1/2 w.	10	19C311166P2	Base line. (Mounts Ll19, 120). (Part of C143)
			R117	3R149P223J	Composition: 22,000 ohms ±5%, 4 w.	11	19A121350P1	Insulator. (Part of C143).
L101	7488079P35	Choke, RF: 2.2 μh ±10%, 0.5 ohm DC res max;	R118	3R78P473K	Composition: 47,000 ohms ±10%, 1 w.	12	19A122526G1	Support, (Part of C145),
		sim to Jeffers 4412-9K.	R120*	3R77P472J	Composition: 4700 ohms ±5%, 1/2 w.	13	19A122516P1	Slide. (Part of C145).
L102	19A122524G2	Coil,			In 19E500865Gl of REV A and earlier:	14	19A122709Pl	Screw, set: sim to N174P1314. (Part of C145).
L103	19A122524G1	Coil.			In 19E500865G2 of REV C and earlier:	15	7137968P8	Nut, stamped: thd size No. 6-32; sim to Palnut T0632005. (Part of Cl21, 122, and Cl45).
L105	7488079P33	Choke, RF: 1 μh $\pm 10\%$, 0.15 ohm DC res max; sim to Jeffers 4412-5K.	R123	3R77P473K 3R77P152K	Composition: 47,000 ohms ±10%, 1/2 w. Composition: 1500 ohms ±10%, 1/2 w.	16	19A122518G1	T0632005. (Part of Cl21, 122, and Cl45). Dehydrator. (Part of Cl45).
L107	19B205615P2	Coil.	R124	19B209381P1	Variable, composition: 10,000 ohms ±20%, 3 w;	17	19C303544P2	Cover. (Used with V103).
L108	19B205615P1	Coil.			sim to Allen-Bradley Type K.	18	19D402783P5	Plate line. (Used with L120).
L110	19B205614P2	Coil.	R125	3R149P153K	Composition: 15,000 ohms ±10%, 4 w.	19	19C311164P4	Plate line. (Used with Ll20).
L111	19B205614P5	Coil.	R126	3R79P562K	Composition: 5600 ohms ±10%, 2 w.	20	19C303405P2	Casting. (Part of Cl21, 122).
L112	19B205614P4	Coil.	R129	3R78P391J	Composition: 390 ohms ±5%, 1 w.	21	4031593P1	Washer. (Part of C144).
L113	19B205614P3	Coil,	R130	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.	22	4032084Pl	Insulator, washer. (Part of C144).
L115	4036032P5	Feed-thru: sim to Sealectro FT-SM-10.	R131	3R79P183K	Composition: 18,000 ohms ±10%, 2 w.	23	19B204395G2	Chassis.
L116		Part of can assembly 19B205625Gl. Not recom- mended as a replaceable item.	R132	3R79P303J	Composition: 30,000 ohms ±5%, 2 w.	24	19B204393P1	(Not Used).
L117	7772834P7	Choke, RF: 0.2 uh ±10%, .034 ohm ±15% DC res.		1		25	19B204394P1	(Not Used).
		320 to 520 MHz freq range; sim to Ohmite Z-460.	\$101	4031922P1	Pushbutton: SPST, normally open, 1/2 amp at	26	19C303495G8	Station Top Cover (except Repeaters and VM).
L119 and		Refer to Mechanical Parts (RC-1593), items 9 and 19.		1	12 VDC; sim to Stackpole Type SS-15.		19C3O3673G3	Station Top Cover (Repeaters and VM only).
L120					TERMINAL BOARDS		19C3O3396G1	Mobile Top cover.
L122	7772834P7	Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC res, 320 to 520 MHz freq range; sim to Ohmite Z-460.	TB1	7775500 P 9	Phen: 5 terminals.	27	4036765G4	Screw: No. 6-32. (Part of Cl21, 122).
L124	19Al21390Pl	Coil,	тв6	7775500P10	Phen: 4 terminals.	28	19A121676P1	Guide pin: 4-40 thread. (Used with J101).
L125	19B205616P1	Coil.	тв9	7487424P1	Miniature, phen: 1 terminal.	29	4036899P4	(Not Used).
and L126			TB10	7487424P2	Miniature, phen: 1 terminal.	30	4036765G2	(Not Used).

SYMBOL	G-E PART NO	DESCRIPTION
31 32 33 34 35 36	4031594P1 4036921P1 19B204366P1 4038930P1 4029030P10 19C303396G7 19C303396G3 19A121065P1 19A121257G1	Insulator. (Part of C144). Bracket, angle: sim to Tinnerman C17609-8A-67. Support. Clip. (Mounts R104).' (Not Used). Station Bottom Cover. Mobile Bottom cover. (Not Used). (Not Used).

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - Models 19E500865G1 & G2

To improve manufacturing procedures. Changed items 8, 9, 10, 18, and 19 of Mechanical Parts List.

REV. B - Model 19E500865G2

To increase grid drive. Deleted Cl35. Added Cl60.

REV. C - To increase grid drive. Changed C119.

REV. D - Model 19E500865G2

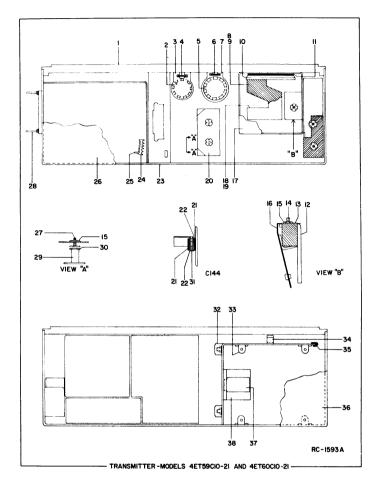
Optimize circuit for new varactor. Replace CV101. Change R120 and R114.

REV. B - Model 19E500865G1

Optimize circuit for new varactor. Replace CV101 Change R114 and R120.

REV. C - Model 19E500865G1

To increase grid drive. Deleted Cl55. Added Cl60.



PARTS LIST

LBI-3936E

CHANNEL GUARD ENCODER G102 4EH17A10 19C311802-G2 REV A

SYMBOL	GE PART NO.	DESCRIPTION
C1*	19A116080-P103	
	19B209243-P2	Polyester: 0.015 µf ±20%, 50 VDCW.
C2	19A116080-P3	Polyester: 0.022 µf ±20%, 50 VDCW.
сз	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C4	19A116080-P9	Polyester: 0.22 μf ±20%, 50 VDCW.
C5	19A116080-P8	Polyester: 0.15 μf ±20%, 50 VDCW.
C6	19A116080-P3	Polyester: 0.022 µf ±20%, 50 VDCW.
C7	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C8	19B209243-P14	Polyester: 0.33 μf ±20%, 250 VDCW.
C9	5496267-Pl	Tantalum: 6.8 μ f $\pm 20\%$, 6 VDCW; sim to Sprague Type 150D.
C10	19A116080-P109	Polyester: 0.22 µf ±10%, 50 VDCW.
Cll thru Cl3	5494481-P111	Ceramic disc: .001 μ f $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
		DIODES AND RECTIFIERS
CR1 and CR2	19A115250-P1	Silicon.
FL1		TONE FREQUENCY NETWORK 19B205280
	198205280-G2 198205280-G2 198205280-G3 198205280-G4 198205280-G5 198205280-G6 198205280-G6 198205280-G6 198205280-G9 198205280-G1 198205280-G2 198205280-G2 198205280-G2 198205280-G2 198205280-G2 198205280-G2 198205280-G2 198205280-G2	71.9 Hz 77.0 Hz 82.5 Hz 88.5 Hz 94.8 Hz 100.0 Hz 103.5 Hz 110.9 Hz 114.8 Hz 118.8 Hz 123.0 Hz 127.3 Hz 131.8 Hz 136.5 Hz 146.2 Hz 146.2 Hz 156.7 Hz 167.9 Hz 167.9 Hz 173.8 Hz 173.8 Hz 173.8 Hz
J1 thru J6	4033513-P4	Contact, electrical; sim to Bead Chain L93-3.
1		TRANSISTORS
Q1 and Q2	19A115123-P1	Silicon, NPN; sim to Type 2N2712.
Q3 thru Q5	19A115362-P1	Silicon, NPN; sim to Type 2N2925.
		RESISTORS
R1	3R77-P333K	Composition: 33,000 ohms ±10%, 1/2 w.

SYMBOL	GE PART NO.	DESCRIPTION
R2	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R3	3R77-P274K	Composition: 0.27 megohms ±10%, 1/2 w.
R4	3R77-P620J	Composition: 62 ohms ±5%, 1/2 w.
R5	3R77-P822K	Composition: 8200 ohms ±10%, 1/2 w.
R6	3R77-P153K	Composition: 15,000 ohms $\pm 10\%$, 1/2 w.
R7	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
R8	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R9	3R77-P184K	Composition: 0.18 megohms ±10%, 1/2 w.
R10	3R77-P622J	Composition: 6200 ohms ±5%, 1/2 w.
R11	3R77-P330K	Composition: 33 ohms ±10%, 1/2 w.
R12	5495948-P365	Deposited carbon: 46,400 ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument CDI/2MR.
R13	3R77-P682J	Composition: 6800 ohms ±5%, 1/2 w.
R14	3R77-P244J	Composition: 0.24 megohms ±5%, 1/2 w.
R15	19A116278-P233	Metal film: 2150 ohms ±2%, 1/2 w.
R16	19A116278-P301	Metal film: 10,000 ohms ±2%, 1/2 w.
R17	19A116278-P65	Metal film: 46.4 ohms ±2%, 1/2 w.
R18	19A116278-P329	Metal film: 19,600 ohms ±2%, 1/2 w.
R19	19A116278-P285	Metal film: 7500 ohms ±2%, 1/2 w.
R20	19A116278-P412	Metal film: 130,000 ohms ±2%, 1/2 w.
R21	19A116278-P269	Metal film: 5110 ohms ±2%, 1/2 w.
R22	19A116278-P117	Metal film: 147 ohms ±2%, 1/2 w.
R23	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
		THERMISTORS
RT1	5490828-P30	Thermistor: 330,000 ohms ±10%, color code black and gray; sim to Globar Type 783H-3.
RT2	5490828-P36	Thermistor: $55,000$ ohms $\pm 10\%$, color code black and red; sim to Globar Type 723B.
W1		(Part of XFL1).
XFL1	19A121920-G3	Reed, mica-filled phen: 7 pins rated at 1 amp at 500 VRMS with 4-1/4 inches of cable.
		ENCODER INSTALLATION KIT 19A127174-G1
		MISCELLANEOUS
	N404P13C13	Lockwasher, no. 6.
	N80P13005C13	Machine screw, no. 6-32 x 5/16.
	19B201074-P304	Tap screw, no. 6-32 x 1/4.
	N210P13C13	Nut, no. 6-32.
	19B205480-G2	Harness. Includes:
P130 thru P135	4029840-P2	Contact, electrical; sim to Amp 42827-2.

PRODUCTION CHANGES

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REV. A - To improve Channel Guard low pass filter. Changed Cl

^{*}COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

ORDERING SERVICE PARTS

Each component appearing on the schematic diagram is identified by a symbol number, to simplify locating it in the parts list. Each component is listed by symbol number, followed by its description and GE Part Number.

Service parts may be obtained from Authorized GE Communication Equipment Service Stations or through any GE Radio Communication Equipment Sales Office. When ordering a part, be sure to give:

- 1. GE Part Number for component
- 2. Description of part
- 3. 4.
- Model number of equipment Revision letter stamped on unit

These instructions do not purport to cover all details or variations in equipment nor to provide for every possible contingency to be met in connection with installation, operation or maintenance.

Should further information be desired, or should particular problems arise which are not covered sufficiently for the purchaser's purposes, contact the nearest Radio Communication Equipment Sales Office of the General Electric Company.

LBI-4000

F-3136

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY ● LYNCHBURG, VIRGINIA 24502

